

Vishay Siliconix

AUTOMOTIVE

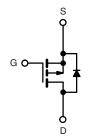
Automotive P-Channel 60 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY | |
|--|--------|
| V _{DS} (V) | -60 |
| $R_{DS(on)} (\Omega)$ at V_{GS} = -10 V | 0.0067 |
| $R_{DS(on)} (\Omega)$ at $V_{GS} = -4.5 V$ | 0.0088 |
| I _D (A) | -120 |
| Configuration | Single |



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- AEC-Q101 qualified d
- 100 % R_g and UIS tested
- ROHS COMPLIANT HALOGEN FREE
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



P-Channel MOSFET

| ORDERING INFORMATION | |
|---------------------------------|------------------|
| Package | TO-220 |
| Lead (Pb)-free and Halogen-free | SQP90P06-07L-GE3 |

| ABSOLUTE MAXIMUM RATING | S (T _C = 25 °C, unles | ss otherwise noted |) | |
|--|---|-----------------------------------|-------------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | | V _{DS} | -60 | v |
| Gate-Source Voltage | | V _{GS} | ± 20 | v |
| Continuous Drain Current ^a | $T_{C} = 25 \ ^{\circ}C^{a}$ | - I _D | -120 | |
| Continuous Drain Current * | T _C = 125 °C | D | -87 | |
| Continuous Source Current (Diode Conduct | on) ^a | ١ _S | -120 | А |
| Pulsed Drain Current ^b | | I _{DM} | -480 | |
| Single Pulse Avalanche Current | L = 0.1 mH | I _{AS} | -80 | |
| Single Pulse Avalanche Energy | L = 0.1 IIIH | E _{AS} | 320 | mJ |
| Manianana Danana Diasinastiana b | T _C = 25 °C | PD | 300 | w |
| Maximum Power Dissipation ^b | T _C = 125 °C | r D | 100 | vv V |
| Operating Junction and Storage Temperature | e Range | T _J , T _{stg} | -55 to +175 | °C |

| THERMAL RESISTANCE RATINGS | | | | |
|----------------------------|------------------------|-------------------|-------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Junction-to-Ambient | PCB Mount ^c | R _{thJA} | 40 | °C/W |
| Junction-to-Case (Drain) | | R _{thJC} | 0.5 | 0/10 |

Notes

a. Package limited.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. When mounted on 1" square Pcb (Fr-4 material).

d. Parametric verification ongoing.

S14-0585-Rev. A, 17-Mar-14

1 For technical questions, contact: <u>automostechsupport@vishay.com</u>



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| PARAMETER | SYMBOL | TES | T CONDITIONS | MIN. | TYP. | MAX. | UNIT | |
|---|--------------------------|---|--|------|--------|--------|------|--|
| Static | • | • | | | • | | 1 | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0, I_D = -250 \ \mu A$ | | -60 | - | - | N | |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = | V_{GS} , I_D = -250 μ A | -1.5 | -2.0 | -2.5 | V | |
| Gate-Source Leakage | I _{GSS} | V _{DS} = | 0 V, V_{GS} = ± 20 V | - | - | ± 100 | nA | |
| Zero Gate Voltage Drain Current | | V _{GS} = 0 V | V _{DS} = -60 V | - | - | -1 | | |
| | I _{DSS} | $V_{GS} = 0 V$ | $V_{DS} = -60 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$ | - | - | -50 | μA | |
| | | V _{GS} = 0 V | V _{DS} = -60 V, T _J = 175 °C | - | - | -250 | | |
| On-State Drain Current ^a | I _{D(on)} | $V_{GS} = -10 V$ | $V_{DS} \le -5 V$ | -120 | - | - | Α | |
| | | V _{GS} = -10 V | I _D = -30 A | - | 0.0056 | 0.0067 | - Ω | |
| Ducia Course On Otata Desistance à | P | V _{GS} = -10 V | I _D = -30 A, T _J = 125 °C | - | - | 0.0110 | | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = -10 V | I _D = -30 A, T _J = 175 °C | - | - | 0.0130 | | |
| | | $V_{GS} = -4.5 V$ | I _D = -20 A | - | 0.0070 | 0.0088 | | |
| Forward Transconductance b | 9 _{fs} | $V_{DS} = -15 \text{ V}, \text{ I}_{D} = -30 \text{ A}$ | | - | 90 | - | S | |
| Dynamic ^b | - | | | | | | | |
| Input Capacitance | C _{iss} | | | - | 11 423 | 14 280 | | |
| Output Capacitance | C _{oss} | $V_{GS} = 0 V$ | V _{DS} = -25 V, f = 1 MHz | - | 1034 | 1295 | pF | |
| Reverse Transfer Capacitance | C _{rss} | 7 | | - | 809 | 1015 | | |
| Total Gate Charge ^c | Qg | | | - | 180 | 270 | | |
| Gate-Source Charge ^c | Q _{gs} | V _{GS} = -10 V | $V_{DS} = -30 \text{ V}, \text{ I}_{D} = -110 \text{ A}$ | - | 31 | - | nC | |
| Gate-Drain Charge ^c | Q _{gd} | _ | | - | 43 | - | 1 | |
| Gate Resistance | R _g | f = 1 MHz | | 1.1 | 2.27 | 3.5 | Ω | |
| Turn-On Delay Time ^c | t _{d(on)} | | | - | 15 | 23 | | |
| Rise Time ^c | t _r | V _{DD} = | $V_{DD} = -30 \text{ V}, \text{ R}_{\text{I}} = 0.27 \Omega$ | | 23 | 35 | ns | |
| Turn-Off Delay Time ^c | t _{d(off)} | $I_D \cong -110 \text{ A}, \text{ V}_{\text{GEN}} = -10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$ | | - | 97 | 146 | | |
| Fall Time ^c | t _f | | | - | 32 | 48 | | |
| Source-Drain Diode Ratings and Chara | acteristics ^b | <u> </u> | | | | | | |
| Pulsed Current ^a | I _{SM} | | | - | - | -480 | А | |
| Forward Voltage | V _{SD} | I _F = -100 A, V _{GS} = 0 | | - | -0.95 | -1.5 | V | |

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

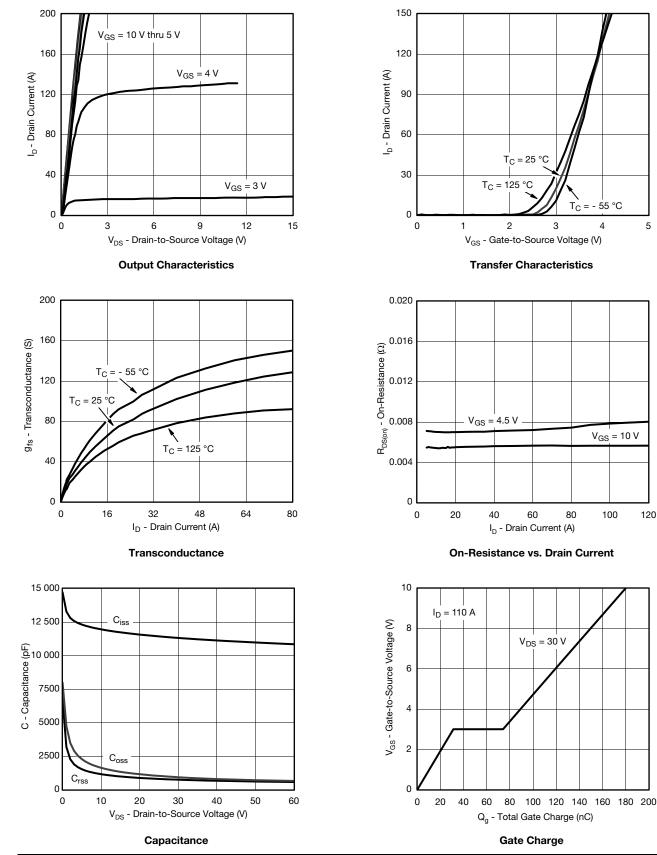
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SQP90P06-07L

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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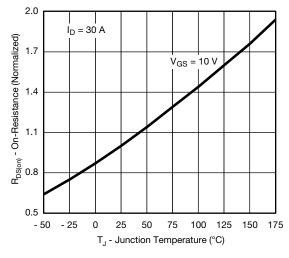
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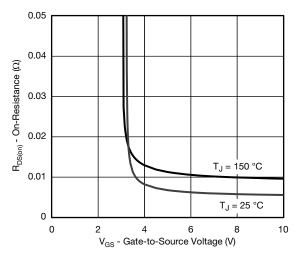
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



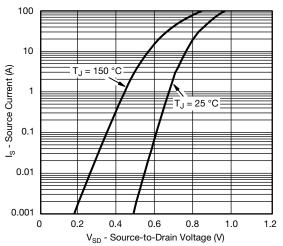
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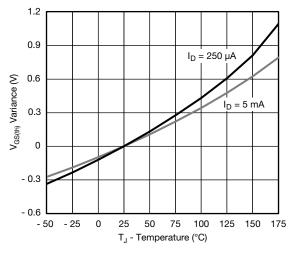
On-Resistance vs. Junction Temperature



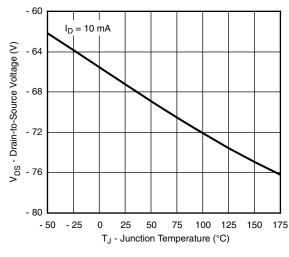
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







Drain Source Breakdown vs. Junction Temperature 4

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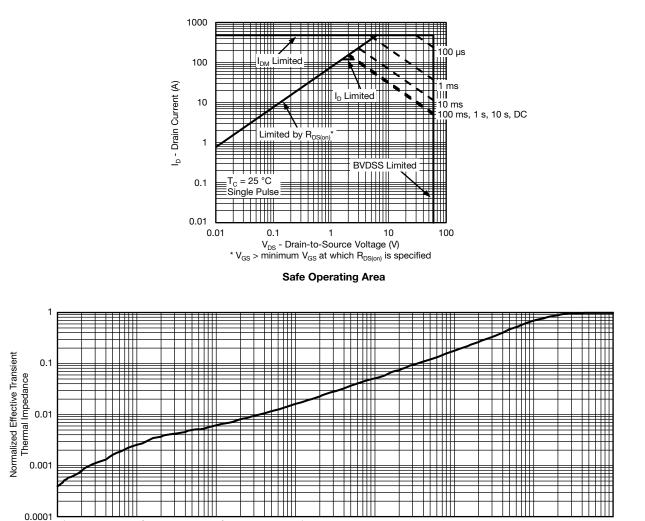
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Square Wave Pulse Duration (s)

1

10

100

10-

Normalized Thermal Transient Impedance, Junction-to-Ambient

. 10⁻⁴ 10⁻³

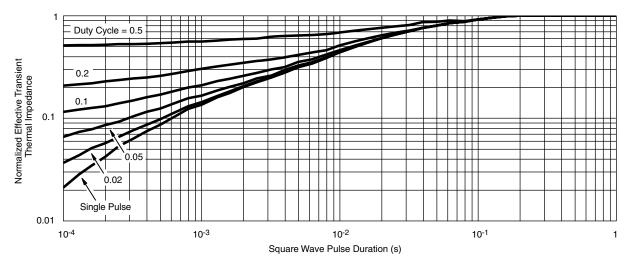
10⁻²

1000



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

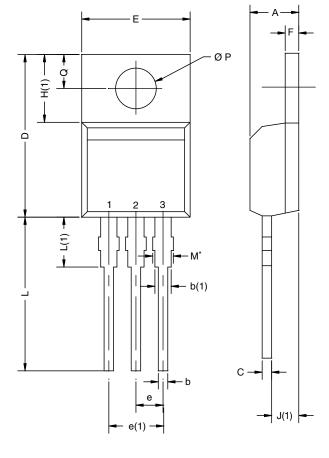
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several gualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62665.



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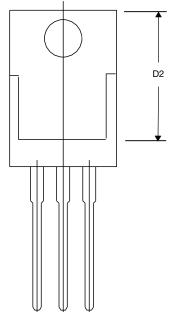
TO-220AB



| | MILLIN | IETERS | INCHES | | |
|-----------------------|-------------------|-----------|--------|-------|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | |
| А | 4.25 | 4.65 | 0.167 | 0.183 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b(1) | 1.20 | 1.73 | 0.047 | 0.068 | |
| с | 0.36 | 0.61 | 0.014 | 0.024 | |
| D | 14.85 | 15.49 | 0.585 | 0.610 | |
| D2 | 12.19 | 12.70 | 0.480 | 0.500 | |
| Е | 10.04 | 10.51 | 0.395 | 0.414 | |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e(1) | 4.88 | 5.28 | 0.192 | 0.208 | |
| F | 1.14 | 1.40 | 0.045 | 0.055 | |
| H(1) | 6.09 | 6.48 | 0.240 | 0.255 | |
| J(1) | 2.41 | 2.92 | 0.095 | 0.115 | |
| L | 13.35 | 14.02 | 0.526 | 0.552 | |
| L(1) | 3.32 | 3.82 | 0.131 | 0.150 | |
| ØΡ | 3.54 | 3.94 | 0.139 | 0.155 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| ECN: T14- DWG: 547 | 0413-Rev. P, 1 | 16-Jun-14 | | | |

Note

* M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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